









	<h2 style="color: red;">FQU2N90TU</h2>
	Hersteller-Teilenummer: FQU2N90TU
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 900V 1.7A IPAK
	Datenblätter: <ul style="list-style-type: none">  1.FQU2N90TU.pdf  2.FQU2N90TU.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 2695 pcs Stock Available.
	Liefern von: Hong Kong
	Versandweg: DHL/Fedex/TNT/UPS/EMS
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQU2N90TU
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 900V 1.7A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	2695 pcs Stock
detaillierte Beschreibung	N-Channel 900V 1.7A (Tc) 2.5W (Ta), 50W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-PAK
Verlustleistung (max)	2.5W (Ta), 50W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	900V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	1.7A (Tc)
Rds On (Max) @ Id, Vgs	7.2 Ohm @ 850mA, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	500pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































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Sie können auch interessiert sein:

 <p>FQU2N90S FSC FSC TO-251</p>	 <p>FQU2N80TU Fairchild/ON Semiconductor MOSFET N-CH 800V 1.8A IPAK</p>	 <p>FQU2N90TU-WS AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 1.7A IPAK</p>	 <p>FQU2N90TU_AM002 Fairchild/ON Semiconductor MOSFET N-CH 900V 1.7A IPAK</p>
 <p>FQU2N90TU Fairchild/ON Semiconductor MOSFET N-CH 900V 1.7A IPAK</p>	 <p>FQU2N80TU AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 1.8A IPAK</p>	 <p>FQU2N90TU_WS Fairchild/ON Semiconductor MOSFET N-CH 900V 1.7A IPAK</p>	 <p>FQU2N90 FSC FQU2N90 FSC</p>

heiße Teile

Mehr

 FQU17N08L	 FQU17P06	 FQU17P06TU	 FQU17P06TU	 FQU1N50C
 FQU1N60B	 FQU1N60C	 FQU1N60CTU	 FQU1N60CTU	 FQU1N80TU
 FQU1N80TU	 FQU20N06	 FQU20N06L	 FQU20N06LTU	 FQU20N06LTU
 FQU2N50B	 FQU2N50BTU	 FQU2N50BTU	 FQU2N60/SSU2N60	 FQU2N60A
 FQU2N60B	 FQU2N60C	 FQU2N60CTU	 FQU2N60CTU	 FQU2N65C
 FQU2N90TU	 FQU30N06L	 FQU3N40TU	 FQU3N40TU	 FQU3N50C
 FQU3N50CTU	 FQU3N50CTU	 FQU3N60C	 FQU3N60CTU	 FQU3N60CTU
 FQU3N60TU	 FQU3N60TU	 FQU4N20LTU	 FQU4N20TU	 FQU4N20TU
 FQU4N25TU	 FQU4N25TU	 FQU4N50TU	 FQU4N50TU	 FQU4N50TU_WS
 FQU4N60C	 FQU4P25TU	 FQU4P25TU	 FQU5N40TU	 FQU5N40TU

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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